# Thick Film High Voltage Resistors

### An Excellent Solution for The Voltage Trend in Power Impulse Products

#### Preview

The High Voltage RI82 Precision Series provides an excellent solution for design engineers looking for a compact product with high-voltage capabilities to enable them to design within the voltage trend for power impulse products.

The RI82 resistors use Token's proprietary thick film Metal Glaze resistive element and Serpentine Pattern Design which provides ideal cost efficient, stability, precision, non-Inductive, and high voltage characteristics for a wide range of measurement, voltage divider circuits, and control functions in high voltage power electronics applications.



By utilizing specific 96 % pure alumina materials with optimum processing, Token are able to control, very tightly in manufacturing, the important ultra-stable performance tolerance  $F(\pm 1\%)$ ,  $G(\pm 2\%)$ ,  $J(\pm 5\%)$ ,  $K(\pm 10\%)$ , and  $M(\pm 20\%)$ . Voltage handle up to 30 KV. This unique process is offered in specific resistance values in a wide variety of sizes and terminations. The extraordinary operating stability of the Type RI82 resistors will improve the performance of your high voltage system in precision.

The Precision RI82 High Voltage Series is RoHS compliant and lead free. For customed designs, tighter tolerances, non-standard technical requirements, or custom special applications, please contact our sales for more information.

#### Applications

- Rated Wattage from 0.1W to 30W
- Max Working Voltage from 2KV to 30KV.
- Designs built from customer supplied schematics
- Tough epoxy-based coating and high voltage stability
- Temperature Coefficient: 200 ppm/°C to 300 ppm/°C.
- Resistance Range from 10 Megohm to 1KK Megohms (1 Gegaohms).
- Resistance Tolerance F(±1%), G(±2%), J(±5%), K(±10%), and M(±20%).
- Stable cermet resistive element bonded to a high-purity alumina substrate.

#### Features

- X-ray/imaging equipment, Impulse voltage generators,
- Capacitor crowbar circuits, High voltage snubber circuits, Arc furnace damping,
- Pulse modulators, Radar Pulse-forming networks, Energy research, and EMI/lightning supression.
- Applications include power supplies, transformers and any application requiring operation within an environment where high voltages are used.



- Resistive Element: Thick film
- Substrate: 96 % pure alumina
- Encapsulation: Epoxy base, conformal coating (c style only)
- Terminals: Silver palladium pole, tin plated copper leads

## TOKEN RI82 Thick Film High Voltage Resistors

#### **CHIP Type General Specifications (Unit:mm)**

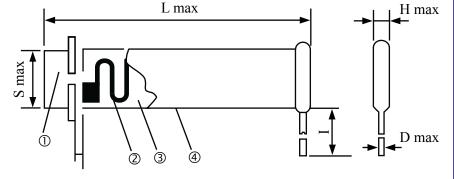
<ul> <li>1 Silver Palladium Pole</li> <li>2 Resistent Film</li> <li>3 Insulation Coating</li> <li>4 96%A1023 Ceramic Base</li> </ul>												
Part Number	Rated Wattage (w)	Style	Dimensions					Resistance Range	Temp Coefficient	Resistance Tolerance	Max Working Voltage	
Inulliber			Lmax	Smax	Hmax	Ι	dmax	(MΩ)	(10 <sup>-6</sup> / °C)	Toteratice	(KV)	
RI82-2	2	а	33	8	0.8			10-1000	<200	$J(\pm 5\%)$	15	
RI82-2	2	а	25	10	0.8			10-1000	≤200	K(±10%) M(±20%)	15	

Remark : Rated Continus Working Voltage (RCWW) shall be determined from RCWW =  $\sqrt{Power Rating \times Resistance Value(\Omega)}$  or Max.Working voltage listed above , whichever two.

### TOKEN RI82 Thick Film High Voltage Resistors

#### **Dip Type General Specification (Unit:mm)**

- ① Silver Palladium Pole
- <sup>(2)</sup> Resistent Film
- ③ Insulation Coating (c style only)
- ④ 96%A1023 Ceramic Base



Part	Rated		D	imensi	ons		Resistance	Temp	Max Working	Resistance
Number	Wattage (w)	$L \pm 2$	$S \pm 2 = H max$		Ι	D max	Range (MΩ)	Coefficient (10 <sup>-6</sup> / °C)	Voltage (KV)	Tolerance
RI82-0.125	0.125	8	3.5	2.5	20.0min	0.56	100-4.7K	≤200	4	
RI82-0.125	0.125	10	5	2.5	24.0min	0.56	100-10K	≤200	4	
RI82-0.25S	0.25S	10	5	2.5	20.0min	0.56	10-1000	≤200	4	
RI82-0.25	0.25	22	4	2.5	20.0min	0.56	100-10K	≤200	4	
RI82-0.25	0.25	25	5	2.5	20.0min	0.56	100-10K	≤200	10	
RI82-0.5	0.5	35	5	2.5	24.0max	0.56	100-10K	≤200	15	
RI82-0.5	0.5	41	5	2.5	42.0max	0.56	100-1KK	≤200	4	F(±1%)
RI82-1	1	25	10	2.5	30.0max	0.56	100-10K	≤200	15	
RI82-1	1	30	8	2.5	30.0max	0.56	100-10K	≤200	15	G(±2%)
RI82-1	1	33	8	2.5	35.0max	0.56	100-10K	≤200	15	I(±50/)
RI82-1	1	38	10	3	45.0max	0.80	10-1000	≤200	20	J(±5%)
RI82-2	2	38	10	3	40.0max	0.80	100-10K	≤200	20	K(±10%)
RI82-2	2	45	10	3	45.0max	0.80	100-10K	≤200	20	
RI82-3	2	50	10	3	45.0max	0.80	100-10K	≤200	20	M(±20%)
RI82-3	3	30	15	3	35.0max	0.80	100-10K	≤200	25	
RI82-3	3	60	10	3	55.0max	0.80	100-100K	≤300	25	
RI82-5	5	80	20	4	60.0max	0.80	100-200	≤300	25	
RI82-10	10	97	23	4	80.0max	0.80	100-200	≤300	30	
RI82-20	20	100	35	4	80.0max	1	100-200	≤300	30	
RI82-30	30	100	48	4	80.0max	1	100-200	≤300	30	

Remark : Rated Continus Working Voltage (RCWW) shall be determined from RCWW =  $\sqrt{\text{Power Rating × Resistance Value}(\Omega)}$  or Max.Working voltage listed above , whichever two.

#### **RI82** Non-Inductive & Serpentine Pattern - Advance Technique

#### **Non-Inductive Performance:**

1. Token's RI82 Non-Inductive Design which uses a serpentine resistive pattern that offers for zigzagging lines to carry current in opposite directions, thereby neutralizing maximum of flux fields over the entire length of the resistor.

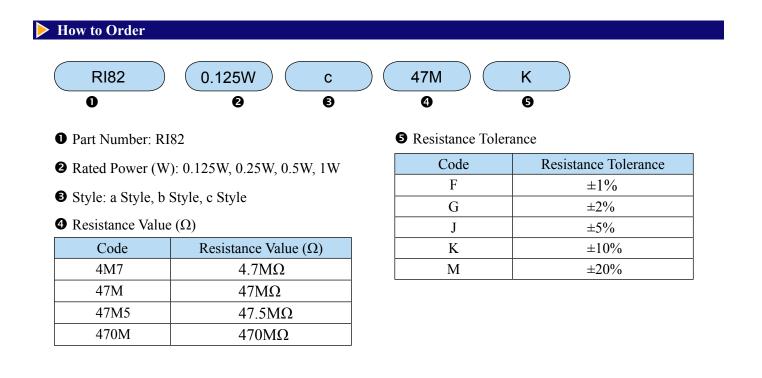
2. This efficient non-inductive construction retains performance advantages and heavy load characteristics which is ideal for high frequency applications.

#### Serpentine Pattern Screen Printing Design:

1. Type RI82 Precision High Voltage Resistors combine Token's Non-Inductive serpentine pattern, high thru-put screen printed silicone coating.

2. The alignment of the gap in the serpentine resistor pattern with the gap in the coating pattern provides a complete encapsulation of the resistor element.

3. The lead assemblies are pressed onto the resistor core, finishing the resistor and providing rugged terminal attachment.



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